PCN Number:	2016011800	15	PCN	Date:	2/1/2016	
Title: Datasheet for	l.	<u>. </u>	1 011	Date	2,1,2010	
Customer Contact:	PCN Manager		Dept:	Оиз	lity Services	
Change Type:	I CIT Manager		рерц.	Qua	iity Services	
		Docian	\\\/.	ofor Rum	n Cito	
Assembly Site		Design Data Sheet		afer Bum		
Assembly Process		Data Sheet		Wafer Bump Material		
Assembly Material		Part number change	_	Wafer Fab Cita		
Mechanical Specifi		Test Site		Wafer Fab Site Wafer Fab Materials		
Packing/Shipping/	Labeling	Test Process				
Notification Details Wafer Fab Process						
Description of Character		tification Details				
Description of Change:		ıncing an information only n	- L:6: L:			
The product datasheet(s) The following change hist	is being update	ed as summarized below.				
TEXAS INSTRUMENTS	Texas					
INSTRUMENTS		SNOSCX2C - SEPTEME	BER 2013-RE			
Changes from Revision B (Mai	rch 2015) to Revisio	n C			Page	
Changed XOUT pin description to clarify proper crystal connection					4	
Added instructions on proper DAP connection						
Added conditions for L measurement resolution						
Added Conditions for L measurement resolution Changed TYP to NOM						
Changed TYP to NOM Changed Some descriptions of device functionality for better clarity and consistency						
Changed Some descriptions of device functionality for better clarity and consistency Changed RP Conversion equation for clarity						
Added extended SPI transaction figure for clarity Changed Register mans to include Clock Configuration and Threshold Registers.						
Changed Register maps to include Clock Configuration and Threshold Registers						
Changed description of Min Sensor frequency for clarity						
Added documentation of registers 0x05, 0x06, and 0x08 Changed description of 000 Status to include passible assess.						
Changed description of OSC Status to include possible causes. 23 24 25 26 27 28 29 20 20 20 20 20 20 20 20 20						
Changed some details on Application Information for improved clarity and consistency					24	
	5	11 11		-	25	
configuration						
The datasheet number wi						
Device Family		Change From:		Change	To:	
LDC1000		SNOSCX2B		SNOSCX2C		
2201000		<u> </u>		2.1000		
These changes may be re http://www.ti.com/production/		atasheet links provided.				
Reason for Change:						
To more accurately reflect	t device charact	eristics.				
,		ction, Quality or Reliabili	ty (pos	itive / r	negative):	
No anticipated impact. Th		tion change announcement				
the actual device.						

Changes to product identification resulting from this PCN:					
None.					
Product Affected:					
LDC1000NHRJ	LDC1000NHRR	LDC1000NHRT			

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com